

#### 30V N-Channel Enhancement Mode MOSFET

Voltage 30 V Current 5.6 A

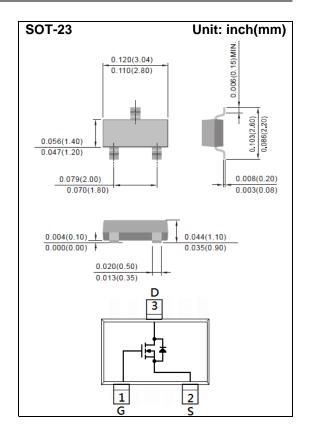
#### **Features**

- RDS(ON) , VGS@10V, ID@5.6A<23mΩ</li>
- RDS(ON) , VGS@4.5V, ID@3.5A<29mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	5.6	Α
Pulsed Drain Current		I <sub>DM</sub>	22	Α
Power Dissipation	T <sub>a</sub> =25°C	_	1.25	W
	Derate above 25°C	P <sub>D</sub>	10	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance		Reja	100	°C/W
- Junction to Ambient <sup>(Note 3)</sup>			100	



## **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.0	1.57	2.1	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5.6A	-	20	23	mΩ	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.5A	-	24	29		
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic <sup>(Note 5)</sup>							
Total Gate Charge	$Q_g$	\/ A5\/   5.0A	-	12.8	-	nC	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =15V, I <sub>D</sub> =5.6A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	1.6	-		
Gate-Drain Charge	$Q_gd$	VGS=10V(Note 1,2)	-	2.5	-		
Input Capacitance	Ciss	\/ 45\/ \/ O\/	-	602	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V,	-	90	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	67	-		
Turn-On Delay Time	td <sub>(on)</sub>	1/ 45\/ 1 5 04	-	4.7	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =15V, I <sub>D</sub> =5.6A,	-	34	-		
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V$ , $R_{G}=3\Omega^{(Note\ 1,2)}$	-	15	-	ns	
Turn-Off Fall Time	tf	RG=312(Note 1,2)	-	17	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	1.5	А	
Diode Forward Current	ls						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.76	1.2	V	

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



#### **TYPICAL CHARACTERISTIC CURVES**

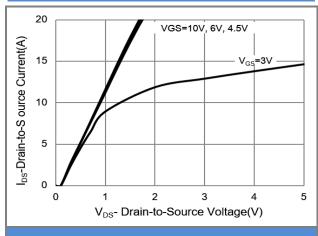
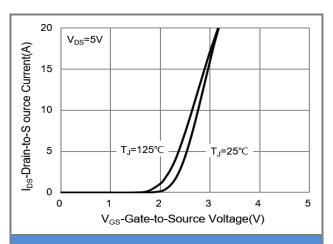


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

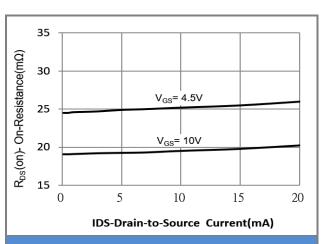


Fig.3 On-Resistance vs. Drain Current

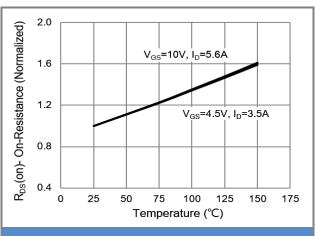
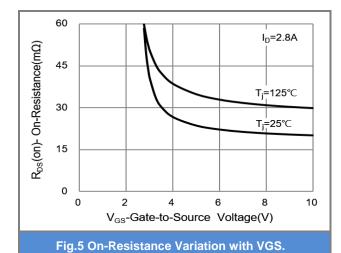


Fig.4 On-Resistance vs. Junction temperature



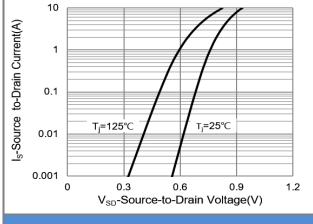


Fig.6 Body Diode Characteristics



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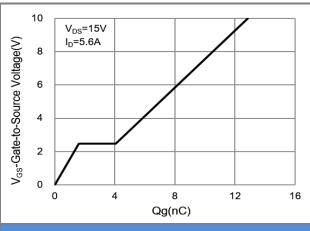


Fig.7 Gate-Charge Characteristics

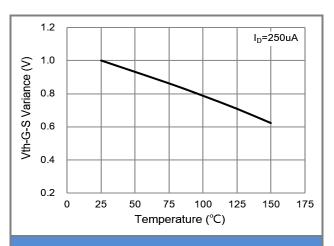


Fig.8 Threshold Voltage Variation with Temperature

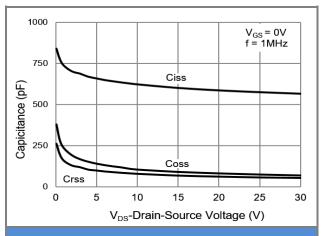


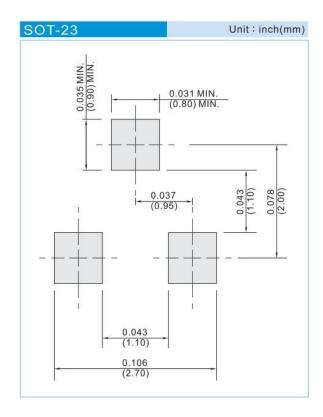
Fig.9 Capacitance vs. Drain-Source Voltage.



## **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJA3404A	SOT-23	3K pcs / 7" reel	A4A	

## **Mounting Pad Layout**





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